

# NPN small signal transistor

## SSTA13

#### Features

(1) High Current Gain.

#### Packaging specifications

Туре	Package	Taping
	Code	T116
	Basic ordering unit (pieces)	3000
SSTA13		0

### ●Absolute maximum ratings (Ta=25°C)

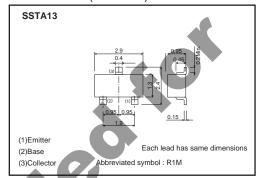
Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	30	V
Collector-emitter voltage	Vces	30	V
Emitter-base voltage	Vево	10	V
Collector current	lc	0.3	A
Collector power dissipation	Pc	0.2	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to 125	°C

#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVces	30	_		V	Ic= 100μA
Collector-emitter breakdown voltage	ВУсео	30	-	-	V	Ic= 10μA
Emitter-base breakdown voltage	ВУЕВО	10	-0	7	V	Iε= 10μA
Collector-base cutoff current	Ісво	4		0.1	μΑ	Vcb= 30V
Emitter-base cutoff current	I <sub>ЕВО</sub> ◀			0.1	μΑ	V <sub>EB</sub> = 10V
Collector-emitter saturation voltage	VCE(sat)	1	)	1.5	V	Ic/I <sub>B</sub> = 100mA/ 0.1mA
Base-emitter voltage	V <sub>BE(on)</sub>	-		2.0	V	VcE= 5V, Ic= 100mA *
DC current transfer ratio	hfe	5000	-	_		Vce= 5V, Ic= 10mA
DC current transfer fatto		10000	-	_	_	VcE= 5V, Ic= 100mA *
Transition frequency	f⊤	125	_	_	MHz	VcE= 5V, IE= 10mA, f=100MHz
Collector output capacitance	Cob	_	5.4	_	pF	Vcb= 10V, f=100kHz, IE=0

<sup>\*</sup> Pulsed

#### ●Dimensions (Unit : mm)



SSTA13 Data Sheet

#### •Electrical characteristics curves

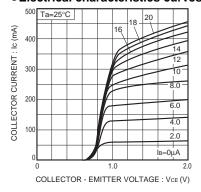


Fig.1 Typical output characteristics (I)

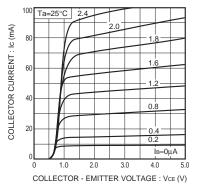


Fig.2 Typical output characteristics (II)

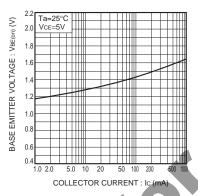


Fig.3 Base emitter 'ON' voltage vs. collector current

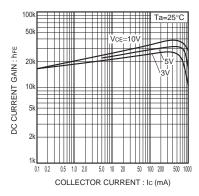


Fig.4 DC current gain vs. collector current (I)

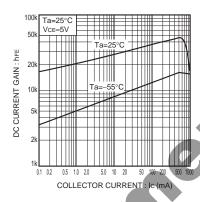


Fig.5 DC current gain vs. collector current ( II )

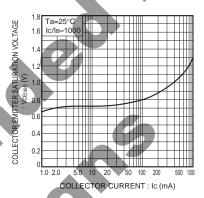


Fig.6 Collector emitter saturation voltage vs. collector current

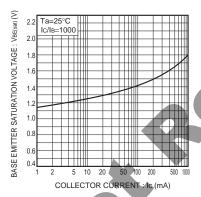


Fig.7 Base emitter saturation voltage vs. collector current

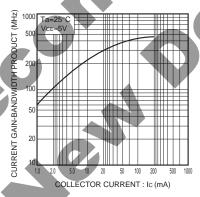


Fig.8 Current gain-bandwidth product vs. collector current

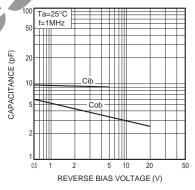


Fig.9 Capacitance vs. reverse bias voltage

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SMMUN2111LT3G SMMUN2113LT1G SMMUN2114LT1G SMMUN2211LT3G SMUN2214T3G SMUN5113DW1T1G
SMUN5335DW1T1G NSBA114YF3T5G NSBC114TF3T5G